

This IC is used for secondary protection of lithium-ion rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits.

Short-circuiting between cells makes it possible for serial connection of three cells to five cells.

■ Features

- High-accuracy voltage detection circuit for each cell
 - Overcharge detection voltage n (n = 1 to 5):
2.700 V to 4.700 V (5 mV step) Accuracy ± 15 mV ($T_a = +25^\circ\text{C}$)
Accuracy ± 20 mV ($T_a = -10^\circ\text{C}$ to $+60^\circ\text{C}$)
 - Overcharge release voltage n (n = 1 to 5)*1:
2.700 V to 4.700 V Accuracy ± 50 mV ($T_a = +25^\circ\text{C}$)
- Overcharge detection delay times are generated only by an internal circuit (external capacitors are unnecessary)
 - Overcharge detection delay time: 0.5 s, 1 s, 2 s, 4 s, 6 s, 8 s
- Output form: CMOS output, Nch open-drain output
- Output logic: Active "H", active "L"
- Built-in test mode function to check overcharge detection voltage with shortened delay time
- High-withstand voltage: Absolute maximum rating 28 V
- Wide operation voltage range: 3.6 V to 26 V
- Wide operation temperature range: $T_a = -40^\circ\text{C}$ to $+85^\circ\text{C}$
- Low current consumption
 - During operation: 1.2 μA typ., 2.4 μA max. ($T_a = +25^\circ\text{C}$)
- Lead-free (Sn 100%), halogen-free

*1. Overcharge release voltage = Overcharge detection voltage + Overcharge hysteresis voltage
(Overcharge hysteresis voltage can be selected from a range of 0 mV to -400 mV in 50 mV step.)

■ Application

- Lithium-ion rechargeable battery pack

■ Packages

- TMSOP-8
- SNT-8A

■ **Block Diagram**

1. CMOS output product

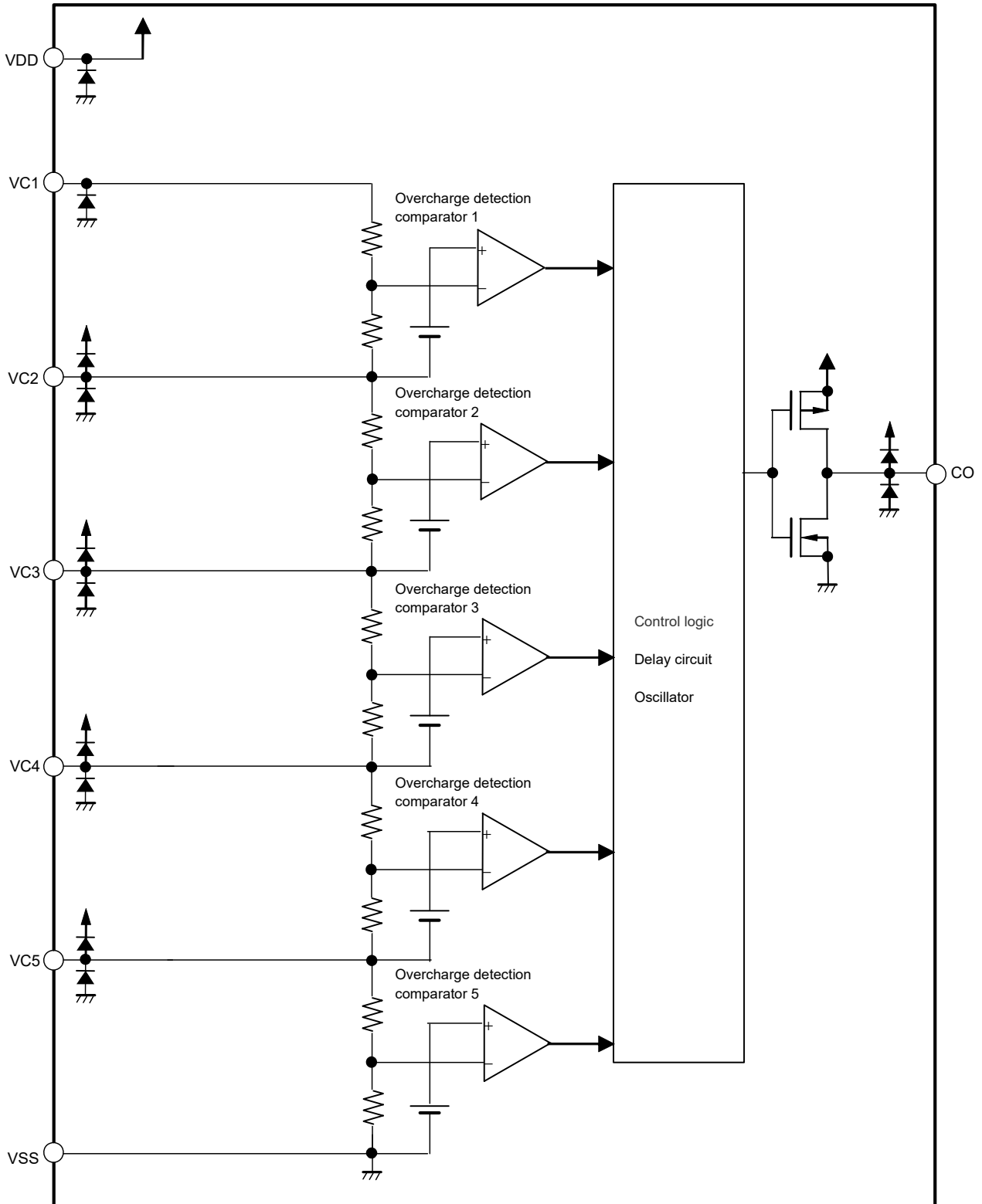


Figure 1

Remark The diodes in the figure are parasitic diodes.

2. Nch open-drain output product

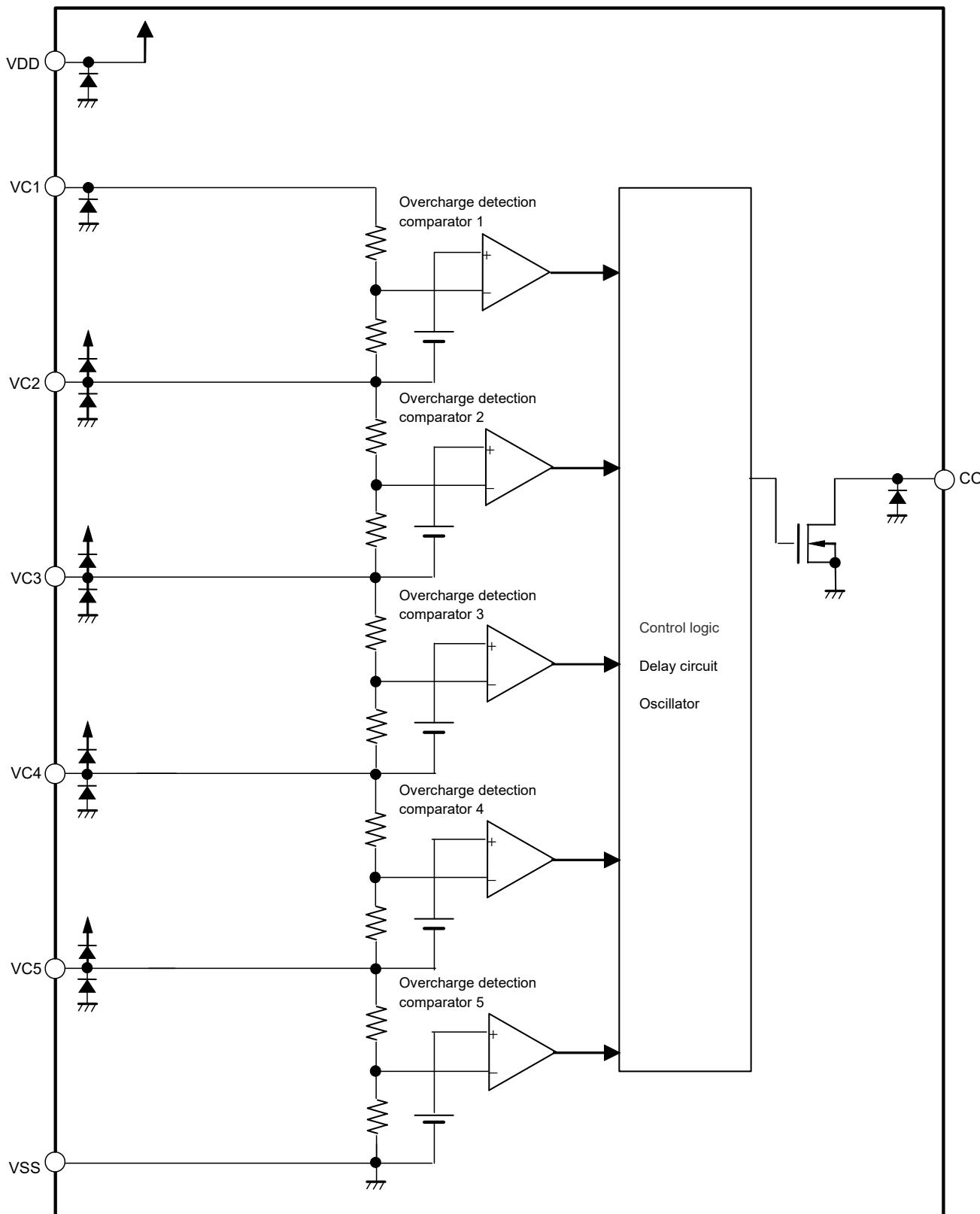
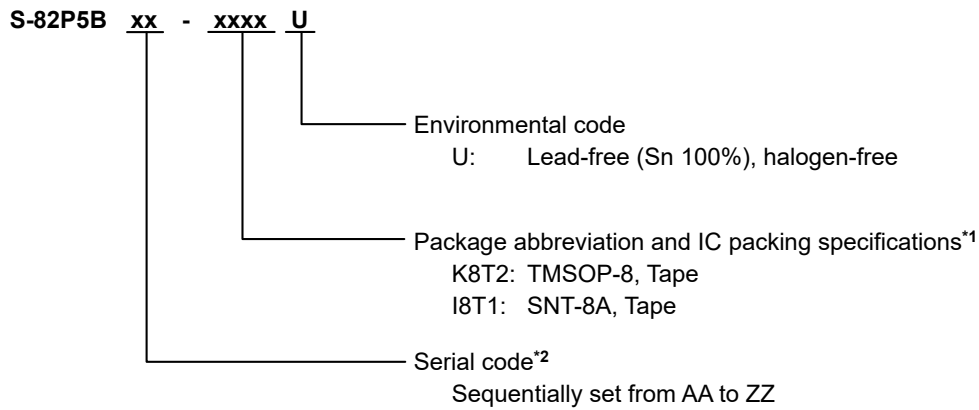


Figure 2

Remark The diodes in the figure are parasitic diodes.

■ **Product Name Structure**

1. **Product name**



*1. Refer to the tape drawing.

*2. Refer to "3. Product name list".

2. **Packages**

Table 1 Package Drawing Codes

Package Name	Dimension	Tape	Reel	Land
TMSOP-8	FM008-A-P-SD	FM008-A-C-SD	FM008-A-R-SD	-
SNT-8A	PH008-A-P-SD	PH008-A-C-SD	PH008-A-R-SD	PH008-A-L-SD

3. **Product name list**

3.1 **TMSOP-8**

Table 2

Product Name	Overcharge Detection Voltage [V _{CU}]	Overcharge Release Voltage [V _{CL}]	Overcharge Detection Delay Time [t _{CU}]	Output Form	Output Logic
S-82P5BAA-K8T2U	4.200 V	4.150 V	1 s	Nch open-drain output	Active "L"

Remark Please contact our sales representatives for products other than the above

■ Pin Configurations

1. TMSOP-8

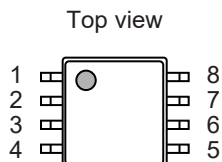


Figure 3

Table 3

Pin No.	Symbol	Description
1	VDD	Input pin for positive power supply
2	VC1	Positive voltage connection pin of battery 1
3	VC2	Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2
4	VC3	Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3
5	VC4	Negative voltage connection pin of battery 3, Positive voltage connection pin of battery 4
6	VC5	Negative voltage connection pin of battery 4, Positive voltage connection pin of battery 5
7	VSS	Input pin for negative power supply, Negative voltage connection pin of battery 5
8	CO	FET gate connection pin for charge control

2. SNT-8A

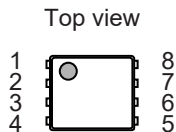


Figure 4

Table 4

Pin No.	Symbol	Description
1	VDD	Input pin for positive power supply
2	VC1	Positive voltage connection pin of battery 1
3	VC2	Negative voltage connection pin of battery 1, Positive voltage connection pin of battery 2
4	VC3	Negative voltage connection pin of battery 2, Positive voltage connection pin of battery 3
5	VC4	Negative voltage connection pin of battery 3, Positive voltage connection pin of battery 4
6	VC5	Negative voltage connection pin of battery 4, Positive voltage connection pin of battery 5
7	VSS	Input pin for negative power supply, Negative voltage connection pin of battery 5
8	CO	FET gate connection pin for charge control

■ **Absolute Maximum Ratings**

Table 5

(Ta = +25°C unless otherwise specified)

Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	V _{DS}	VDD	V _{SS} - 0.3 to V _{SS} + 28	V
Input pin voltage	V _{IN}	VC1	V _{SS} - 0.3 to V _{SS} + 28	V
		VC2, VC3, VC4, VC5	V _{SS} - 0.3 to V _{DD} + 0.3	V
CO pin output voltage	CMOS output product	CO	V _{SS} - 0.3 to V _{DD} + 0.3	V
	Nch open-drain output product		V _{SS} - 0.3 to V _{SS} + 28	V
Operation ambient temperature	T _{opr}	-	-40 to +85	°C
Storage temperature	T _{stg}	-	-40 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

■ **Thermal Resistance Value**

Table 6

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
Junction-to-ambient thermal resistance*1	θ _{JA}	TMSOP-8	Board A	-	160	-	°C/W
			Board B	-	133	-	°C/W
			Board C	-	-	-	°C/W
			Board D	-	-	-	°C/W
			Board E	-	-	-	°C/W
		SNT-8A	Board A	-	211	-	°C/W
			Board B	-	173	-	°C/W
			Board C	-	-	-	°C/W
			Board D	-	-	-	°C/W
			Board E	-	-	-	°C/W

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ Power Dissipation" and "Test Board" for details.

■ Electrical Characteristics

Table 7

(Ta = +25°C unless otherwise specified)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	Test Circuit
Detection voltage							
Overcharge detection voltage n (n = 1, 2, 3, 4, 5)	V _{CU_n}	Ta = +25°C	V _{CU} - 0.015	V _{CU}	V _{CU} + 0.015	V	1
		Ta = -10°C to +60°C*1	V _{CU} - 0.020	V _{CU}	V _{CU} + 0.020	V	1
Overcharge release voltage n (n = 1, 2, 3, 4, 5)	V _{CL_n}	-	V _{CL} - 0.050	V _{CL}	V _{CL} + 0.050	V	1
Input voltage							
Operation voltage between VDD pin and VSS pin	V _{DSOP}	-	3.6	-	26	V	-
Input current							
Current consumption during operation	I _{OPe}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	-	1.2	2.4	μA	2
Current consumption during overdischarge	I _{OPeD}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.4 V	-	1.0	2.0	μA	2
VC1 pin input current	I _{VC1}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	-	-	0.3	μA	3
VC2 pin input current	I _{VC2}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	0.25	0.5	1.0	μA	3
VC3 pin input current	I _{VC3}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	0.25	0.5	1.0	μA	3
VC4 pin input current	I _{VC4}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	-0.50	-0.25	-0.125	μA	3
VC5 pin input current	I _{VC5}	V1 = V2 = V3 = V4 = V5 = V _{CU} × 0.75 V	-0.50	-0.25	-0.125	μA	3
Output current							
CO pin source current	I _{COH}	-	-	-	-20	μA	4
CO pin sink current	I _{COL}	CMOS output product	0.4	-	-	mA	4
CO pin leakage current	I _{COLL}	Nch open-drain output product	-	-	0.1	μA	4
Delay time							
Overcharge detection delay time	t _{CU}	-	t _{CU} × 0.8	t _{CU}	t _{CU} × 1.2	s	1
Overcharge release delay time	t _{CL}	-	1	2	4	ms	1
Overcharge timer reset delay time	t _{TR}	-	6	12	20	ms	1
Transition time to test mode	t _{TST}	-	-	-	10	ms	1

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

■ Test Circuits

1. Overcharge detection voltage n (V_{CU_n}), overcharge release voltage n (V_{CL_n}) (Test circuit 1)

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = V_{CU} - 0.05\text{ V}$, V_1 is gradually increased. When the CO pin output inverts, the voltage V_1 is defined as V_{CU1} .

After setting $V_1 = V_{CU} + 0.05\text{ V}$, V_2 to $V_5 = V_{CL} - 0.05\text{ V}$, V_1 is gradually decreased. When the CO pin output inverts again, the voltage V_1 is defined as V_{CL1} .

V_{CU_n} and V_{CL_n} ($n = 2$ to 5) can be defined in the same way as when $n = 1$.

2. Output current (Test circuit 4)

2.1 CMOS output product

SW1 and SW2 are set to OFF.

2.1.1 Active "H"

(1) CO pin source current (I_{COH})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_6 = 0.5\text{ V}$, SW1 is turned on. I_6 is then defined as I_{COH} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2.1.2 Active "L"

(1) CO pin source current (I_{COH})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_6 = 0.5\text{ V}$, SW1 is turned on. I_6 is then defined as I_{COH} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2.2 Nch open-drain output product

SW1 and SW2 are set to OFF.

2.2.1 Active "H"

(1) CO pin leakage current "L" (I_{COLL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 28\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COLL} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

2.2.2 Active "L"

(1) CO pin leakage current "L" (I_{COLL})

After setting $V_0 = 0\text{ V}$, V_1 to $V_5 = 2.6\text{ V}$, $V_7 = 28\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COLL} .

(2) CO pin sink current (I_{COL})

After setting $V_0 = 0\text{ V}$, $V_1 = 4.8\text{ V}$, V_2 to $V_5 = 2.05\text{ V}$ and $V_7 = 0.5\text{ V}$, SW2 is turned on. I_7 is then defined as I_{COL} .

**3. Overcharge detection delay time (t_{CU}), overcharge release delay time (t_{CL})
(Test circuit 1)**

After setting $V_0 = 0$ V, V_1 to $V_5 = 2.6$ V, V_1 is increased to 4.8 V. The time interval from this increase until the CO pin output inverts is t_{CU} . After that, decrease V_1 down to 2.6 V. The overcharge release delay time (t_{CL}) is the time period until the CO pin output inverts.

**4. Overcharge timer reset delay time (t_{TR})
(Test circuit 1)**

After setting $V_0 = 0$ V, V_1 to $V_5 = 2.6$ V, V_1 is increased to 4.8 V (first rise) and decreased to 2.6 V (V_1 fall) within t_{CU} . After that, V_1 is increased to 4.8 V again (second rise), and measure the time interval until the CO pin output inverts. When the time interval from V_1 fall until the second rise is short, the CO pin output inverts when t_{CU} has elapsed since the first rise. However, if the time interval is gradually made longer, CO pin output inverts when t_{CU} has elapsed since the second rise. The time interval from V_1 fall until the second rise at that time is t_{TR} .

**5. Transition time to test mode (t_{TST})
(Test circuit 1)**

After setting $V_0 = 0$ V, V_1 to $V_5 = 2.6$ V, V_0 is increased to 4.0 V and decreased to 0 V again. When the time interval from when V_0 is increased until it is decreased is long, if V_1 is then increased to 4.8 V, the CO pin output inverts within 40 ms. However, when the time interval from when V_0 is increased until it is decreased is short, if V_1 is then increased to 4.8 V, it takes more than 40 ms for the CO pin output to invert. t_{TST} is the minimum value of the time interval from V_0 rise until V_0 fall under the condition that the CO pin output inverts within 40 ms.

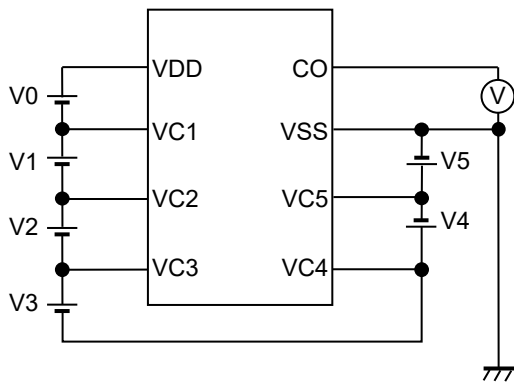


Figure 5 Test Circuit 1

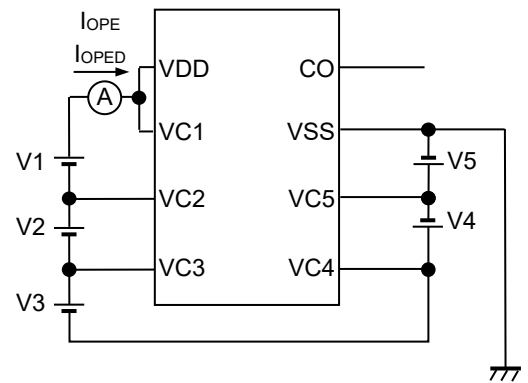


Figure 6 Test Circuit 2

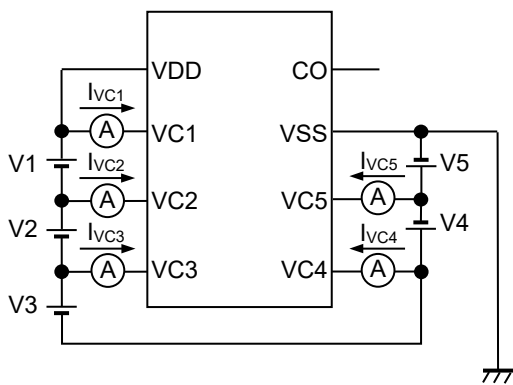


Figure 7 Test Circuit 3

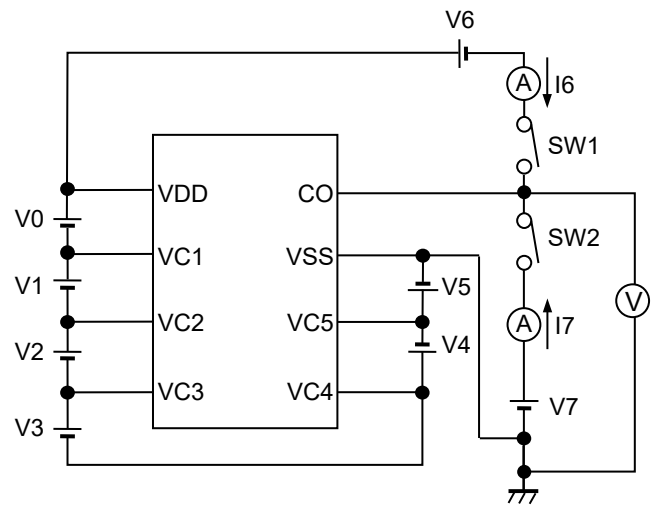


Figure 8 Test Circuit 4

■ Operation

Remark Refer to "■ Battery Protection IC Connection Examples".

1. Normal status

When the voltage of all batteries is lower than overcharge release voltage n (V_{CLn}), "L" (Active "H") or "H" (Active "L") is output from the CO pin. This is the normal status.

2. Overcharge status

When the voltage of any of all batteries exceeds the overcharge detection voltage n (V_{CU_n}) during charging in the normal status and the conditions continue for the overcharge detection delay time (t_{CU}) or longer, the CO pin output inverts. This is the overcharge status. Connecting FET to the CO pin provides charge control and a second protection. If the voltage of all batteries falls to V_{CLn} or lower and the status is retained for the overcharge release delay time (t_{CL}) or longer, this IC returns to the normal status.

3. Overcharge timer reset function

During t_{CU} , which is from when the voltage of any of the batteries being charged exceeds V_{CU_n} until charging stops, this IC has the following operations.

Even if an overcharge release noise, which temporarily forces the battery voltage below V_{CU_n} , is input, t_{CU} is continuously counted as long as the overcharge release noise time is shorter than the overcharge timer reset delay time (t_{TR}). Under the same conditions, if the overcharge release noise time is t_{TR} or longer, counting of t_{CU} is reset once. After that, when V_{CU_n} has been exceeded, counting of t_{CU} resumes.

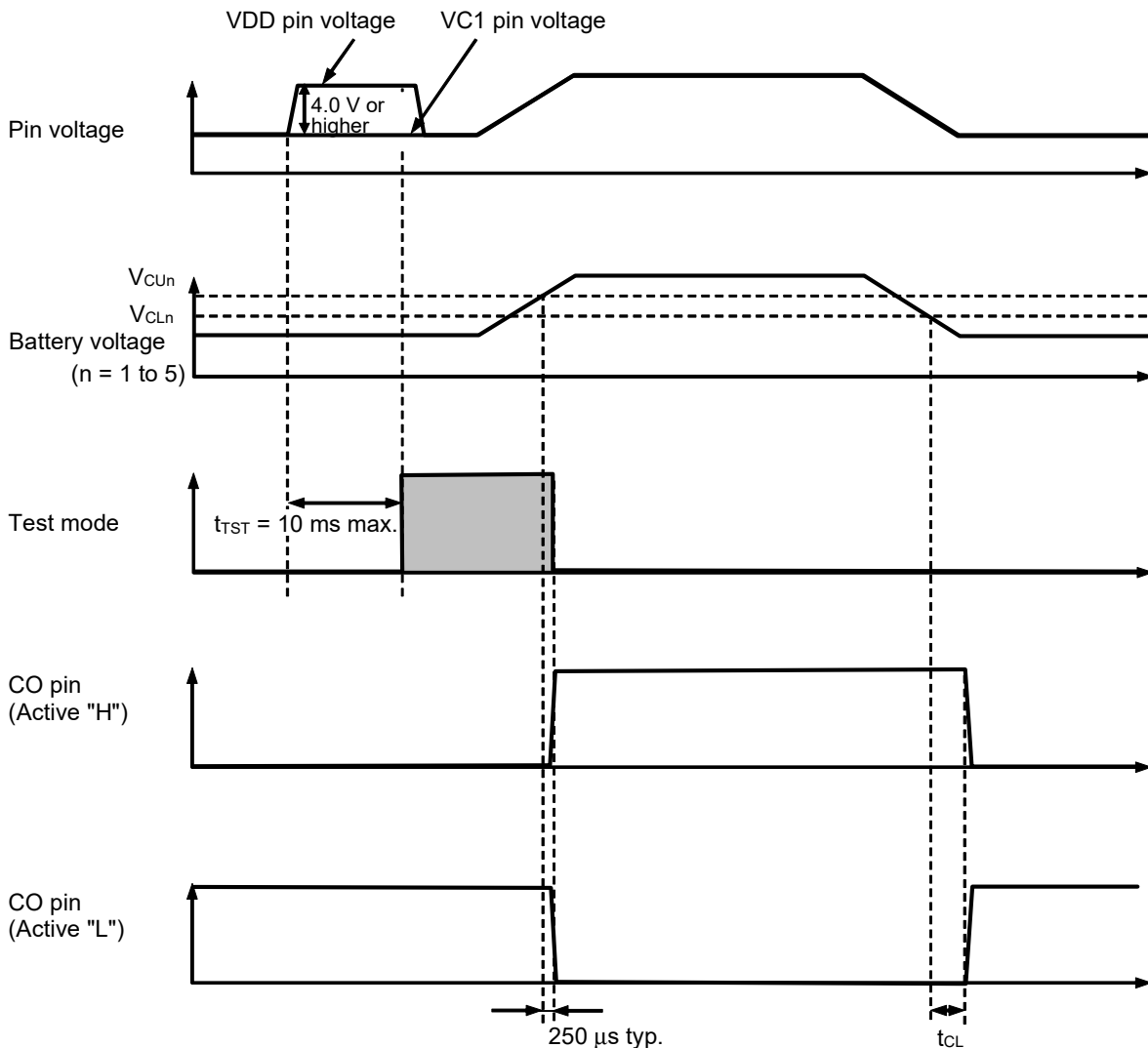
Remark $n = 1$ to 5

4. Test mode

t_{CU} can be shortened by transitioning to the test mode.

This IC transitions to the test mode by retaining the VDD pin voltage at 4.0 V above the VC1 pin voltage or higher for at least transition time to test mode (t_{TST}). The status is retained by the internal latch and the test mode is retained even if the VDD pin voltage is decreased to the same voltage as that of the VC1 pin voltage.

After that, when this IC becomes the overcharge status, the test mode retaining latch is reset and this IC is released from the test mode.



- Caution**
1. Transition to test mode when the voltage of all batteries is lower than V_{CU_n} .
 2. The overcharge timer reset delay time (t_{TR}) is not shortened in the test mode.

Figure 9

■ Timing Charts

1. Overcharge detection operation

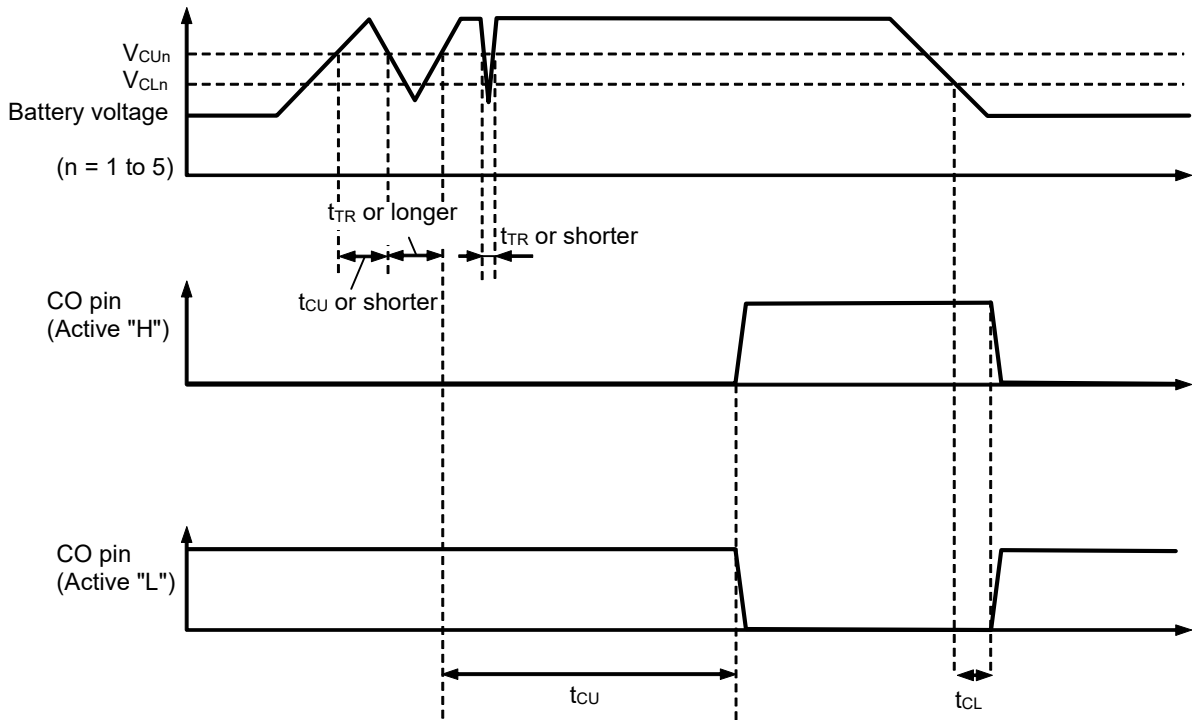


Figure 10

2. Overcharge timer reset function

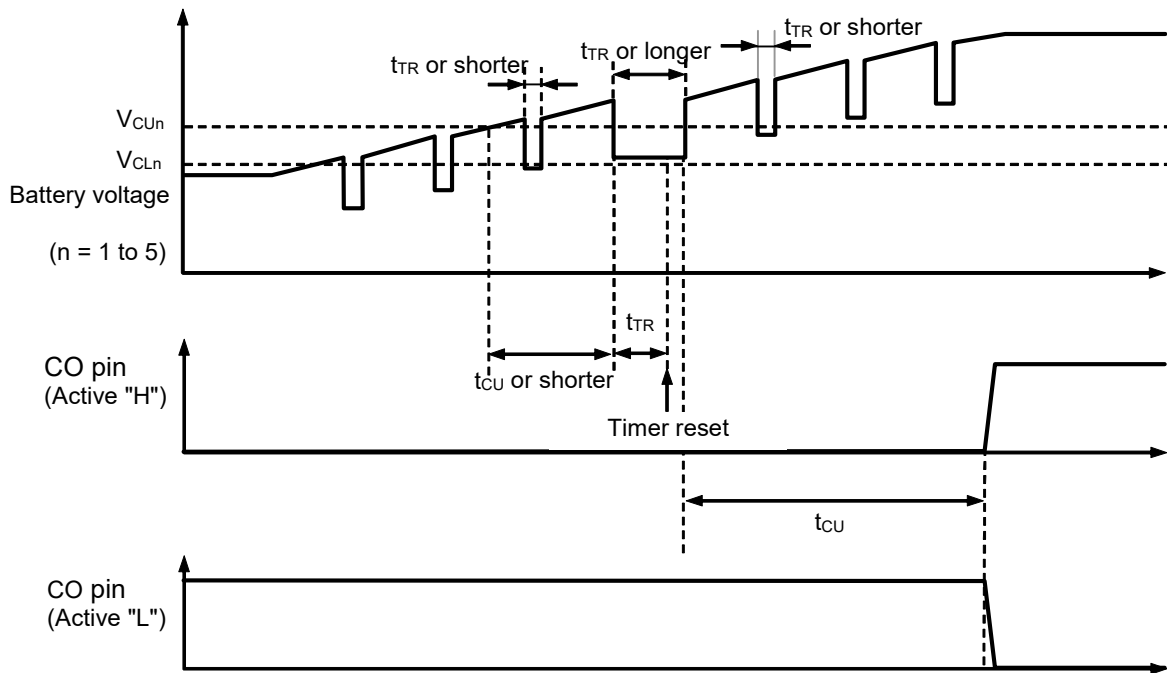


Figure 11

■ Battery Protection IC Connection Examples

1. 5-serial cell (CMOS output product)

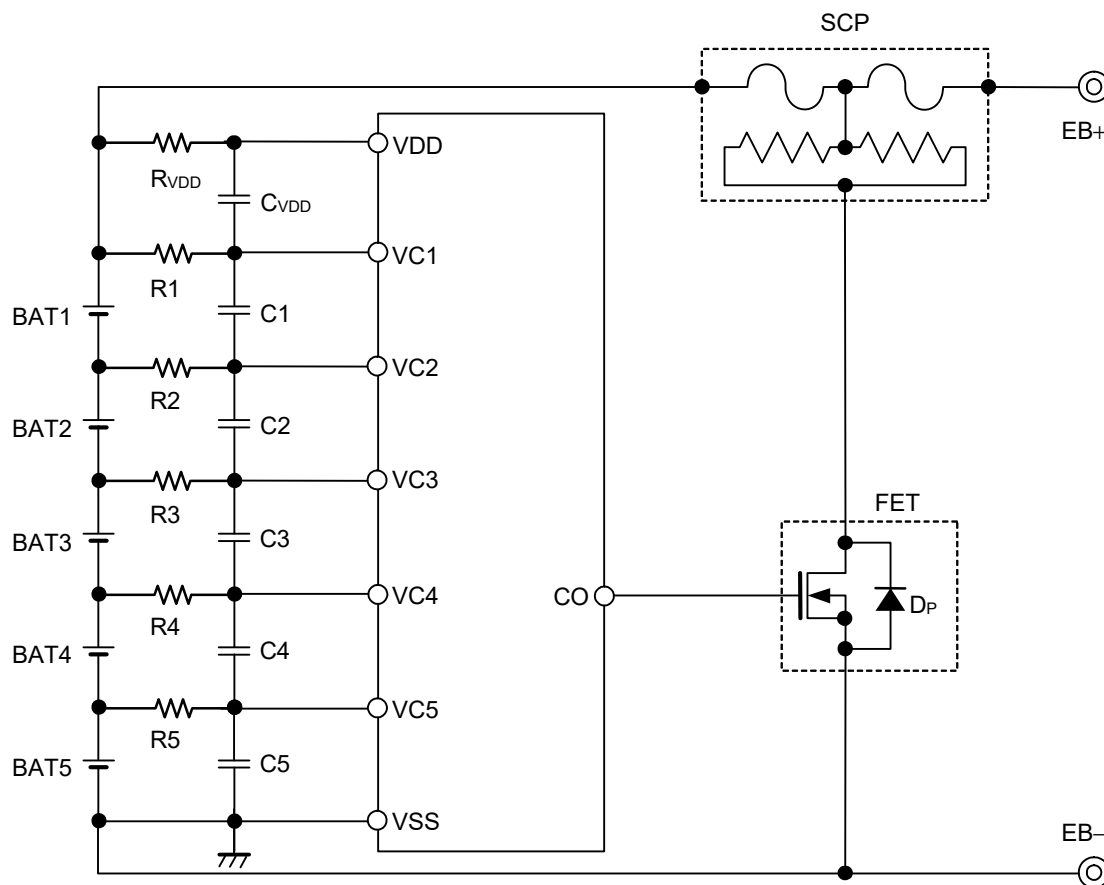


Figure 12

Table 8 Constants for External Components

No.	Symbol	Min.	Typ.	Max.	Unit
1	R1 to R5	100	1000	2000	Ω
2	C1 to C5, CvDD	0.1	0.1	1	μF
3	RvDD	100	100	2000	Ω

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R5 should be the same constant. C1 to C5 and CvDD should be the same constant.

2. 4-serial cell (CMOS output product)

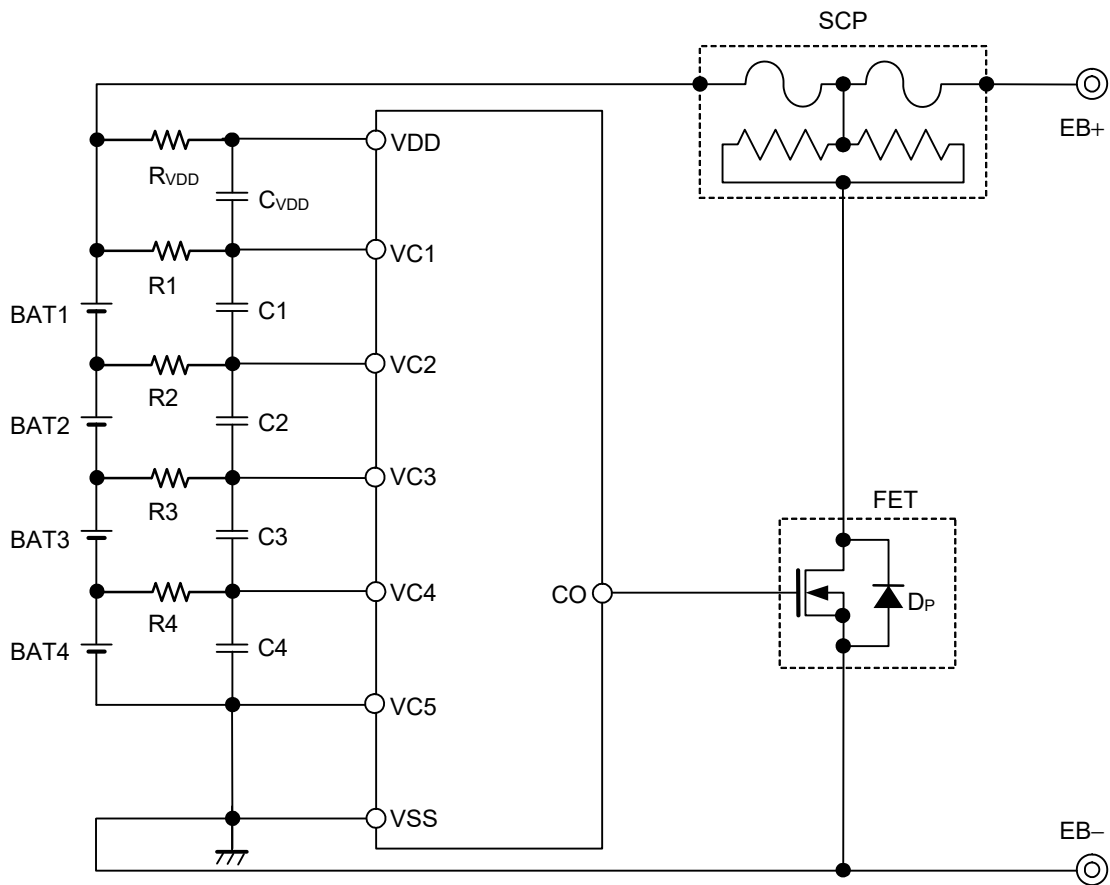


Figure 13

Table 9 Constants for External Components

No.	Symbol	Min.	Typ.	Max.	Unit
1	R1 to R4	100	1000	2000	Ω
2	C1 to C4, C _{VDD}	0.1	0.1	1	μF
3	R _{VDD}	100	100	2000	Ω

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R4 should be the same constant. C1 to C4 and C_{VDD} should be the same constant.

3. 3-serial cell (CMOS output product)

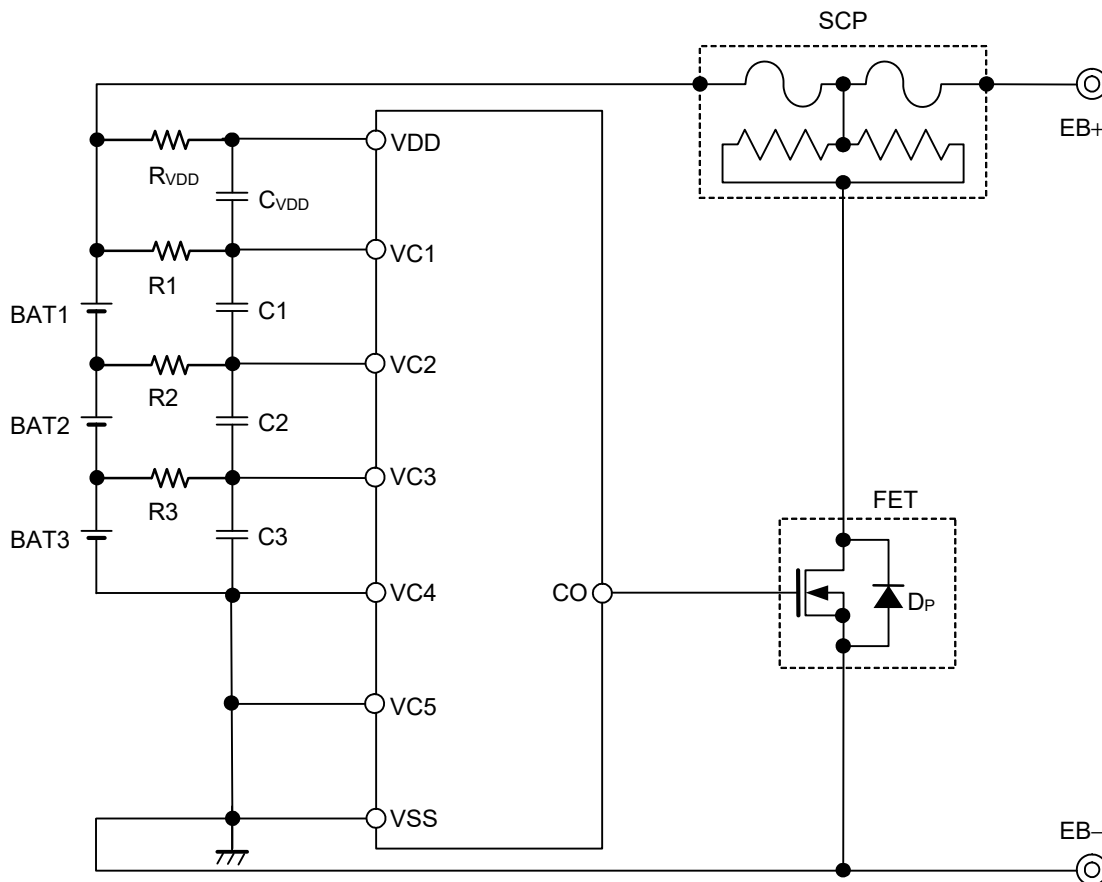


Figure 14

Table 10 Constants for External Components

No.	Symbol	Min.	Typ.	Max.	Unit
1	R1 to R3	100	1000	2000	Ω
2	C1 to C3, C_{VDD}	0.1	0.1	1	μF
3	R_{VDD}	100	100	2000	Ω

- Caution**
1. The constants may be changed without notice.
 2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.
 3. R1 to R3 should be the same constant. C1 to C3 and C_{VDD} should be the same constant.

[For SCP, contact]

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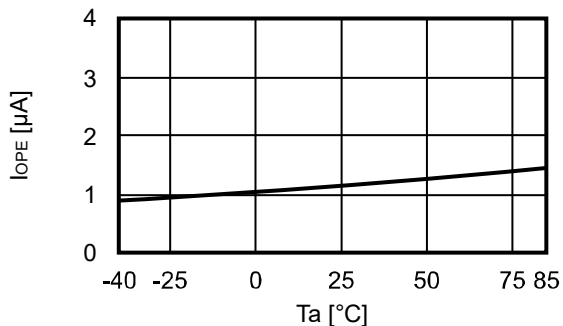
■ Precautions

- Do not connect batteries charged with V_{CLn} or higher. If the connected batteries include a battery charged with V_{CLn} or higher, this IC may become overcharge status after all pins are connected.
- In some application circuits, even if an overcharged battery is not included, the order of connecting batteries may be restricted to prevent transient output of CO detection pulses when the batteries are connected. Perform thorough evaluation with the actual application circuit.
- Before the battery connection, short-circuit the battery side pins R_{VDD} and $R1$, shown in the figure in "**■ Battery Protection IC Connection Examples**".
- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply to this IC an electrostatic discharge that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement of patents owned by a third party by products including this IC.

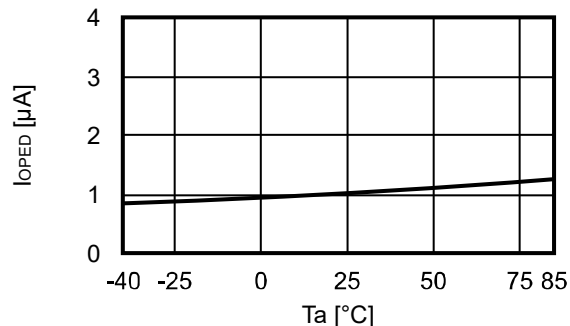
■ Characteristics (Typical Data)

1. Current consumption

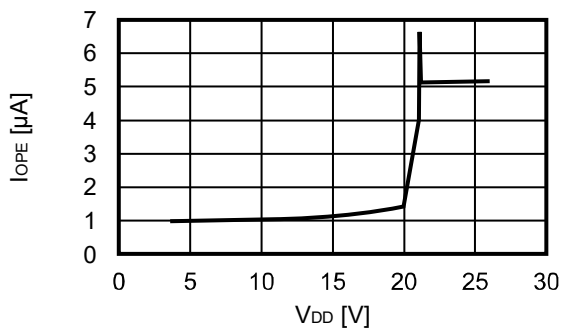
1.1 I_{OPE} vs. T_a



1.2 I_{OPED} vs. T_a

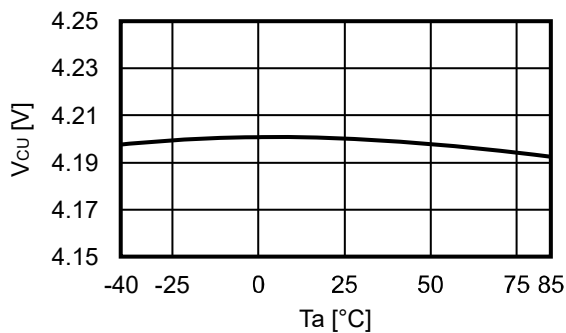


1.3 I_{OPE} vs. V_{DD}

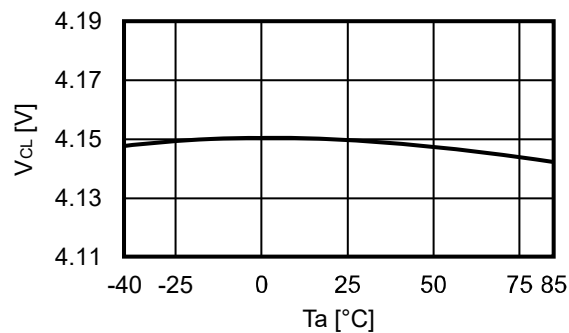


2. Detection voltage

2.1 V_{CU} vs. T_a

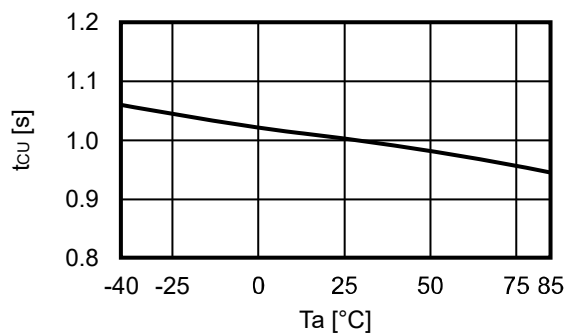


2.2 V_{CL} vs. T_a

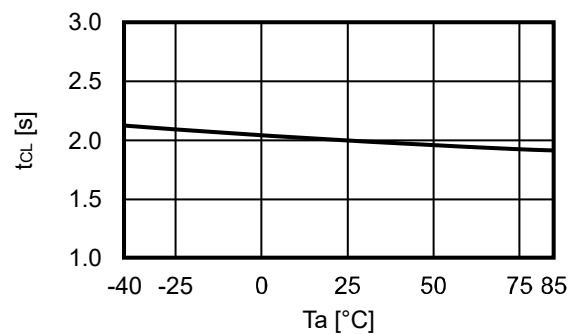


3. Delay time

3.1 t_{CU} vs. T_a

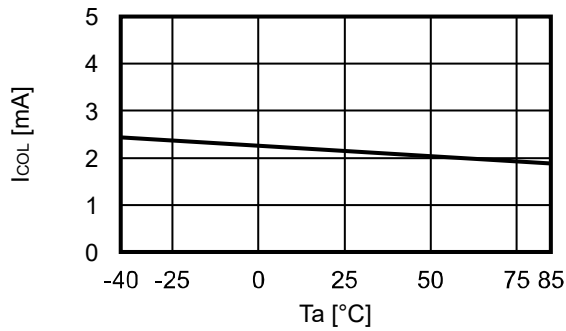


3.2 t_{CL} vs. T_a

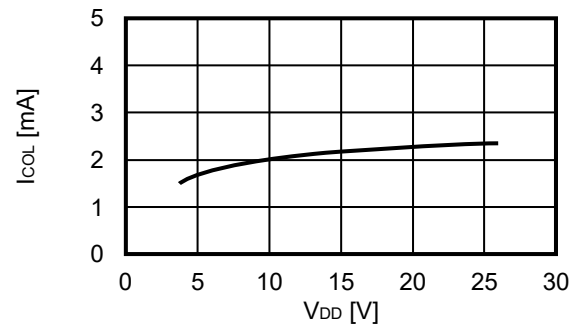


4. Output current

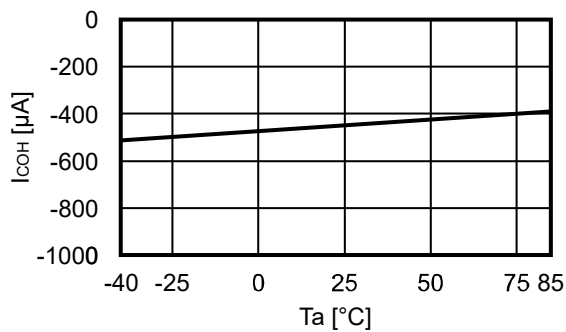
4. 1 I_{COL} vs. Ta



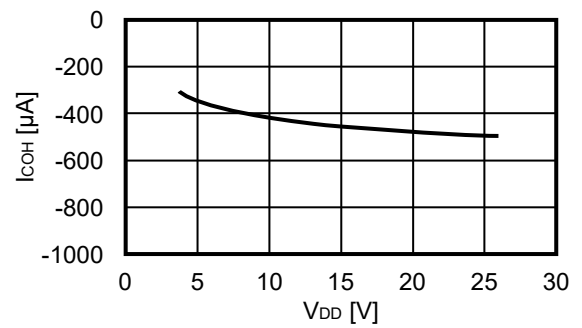
4. 2 I_{COL} vs. V_{DD}



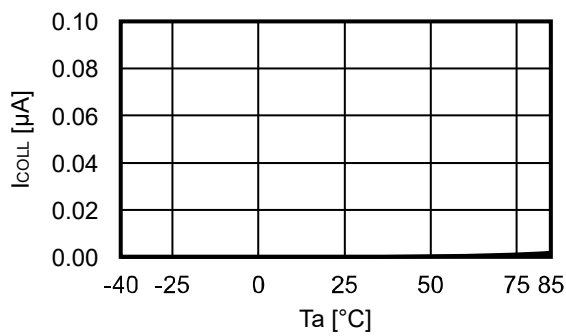
4. 3 I_{COH} vs. Ta



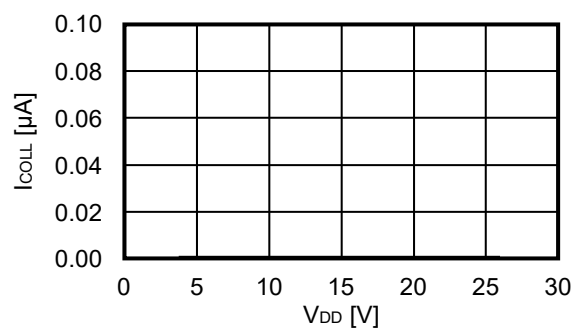
4. 4 I_{COH} vs. V_{DD}



4. 5 I_{COLL} vs. Ta

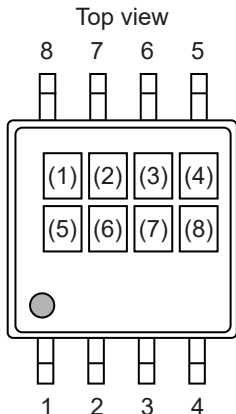


4. 6 I_{COLL} vs. V_{DD}



■ **Marking Specifications**

1. TMSOP-8

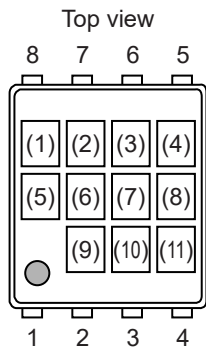


- (1): Blank
- (2) to (4): Product code (Refer to **Product name vs. Product code**)
- (5): Blank
- (6) to (8): Lot number

Product name vs. Product code

Product Name	Product Code		
	(2)	(3)	(4)
S-82P5BAA-K8T2U	9	S	F

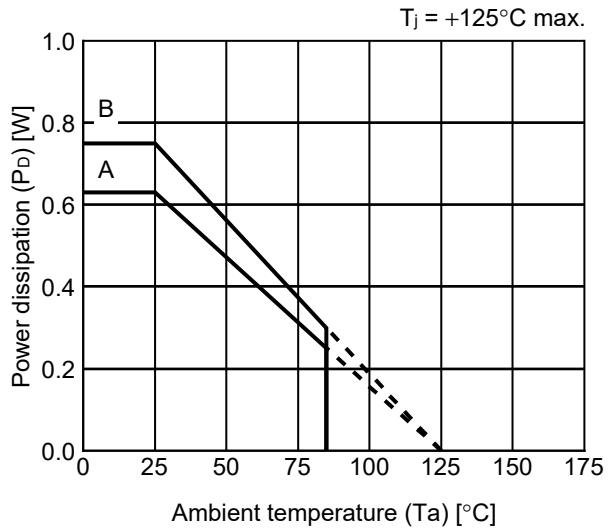
2. SNT-8A



- (1): Blank
- (2) to (4): Product code
- (5), (6): Blank
- (7) to (11): Lot number

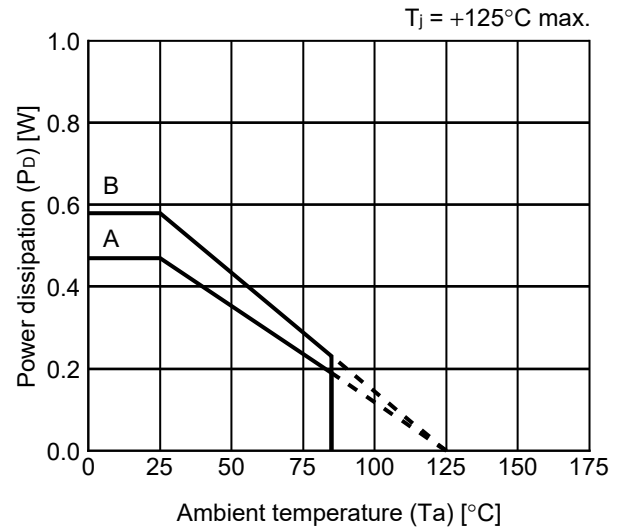
■ **Power Dissipation**

TMSOP-8



Board	Power Dissipation (P _D)
A	0.63 W
B	0.75 W
C	—
D	—
E	—

SNT-8A

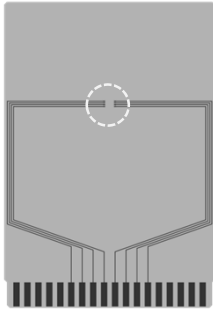


Board	Power Dissipation (P _D)
A	0.47 W
B	0.58 W
C	—
D	—
E	—

TMSOP-8 Test Board

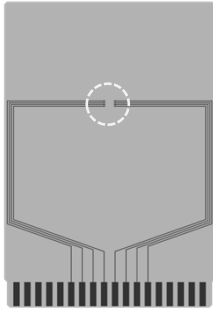
(1) Board A

 IC Mount Area



Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		2
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via		-

(2) Board B



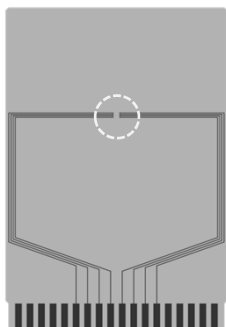
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. TMSOP8-A-Board-SD-1.0

SNT-8A Test Board

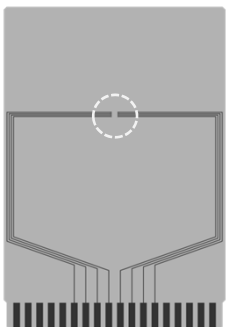
(1) Board A

 IC Mount Area



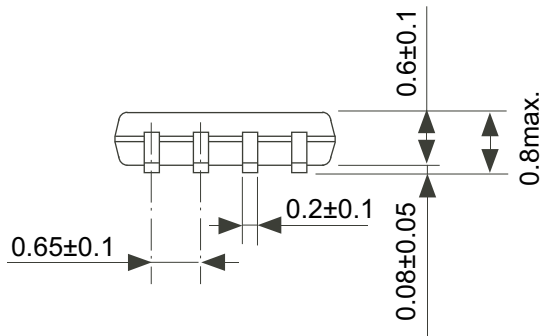
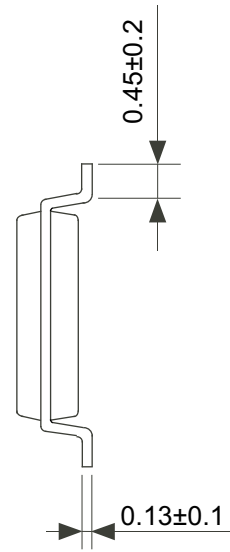
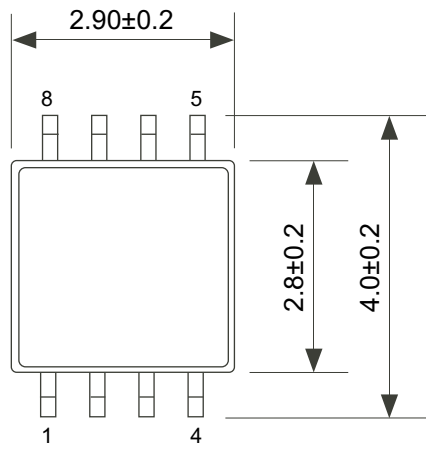
Item	Specification	
Size [mm]	114.3 x 76.2 x t1.6	
Material	FR-4	
Number of copper foil layer	2	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	-
	3	-
	4	74.2 x 74.2 x t0.070
Thermal via	-	

(2) Board B



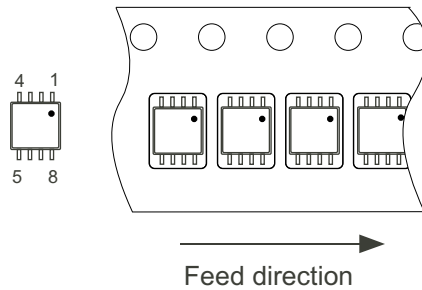
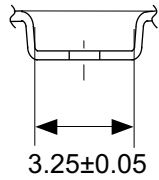
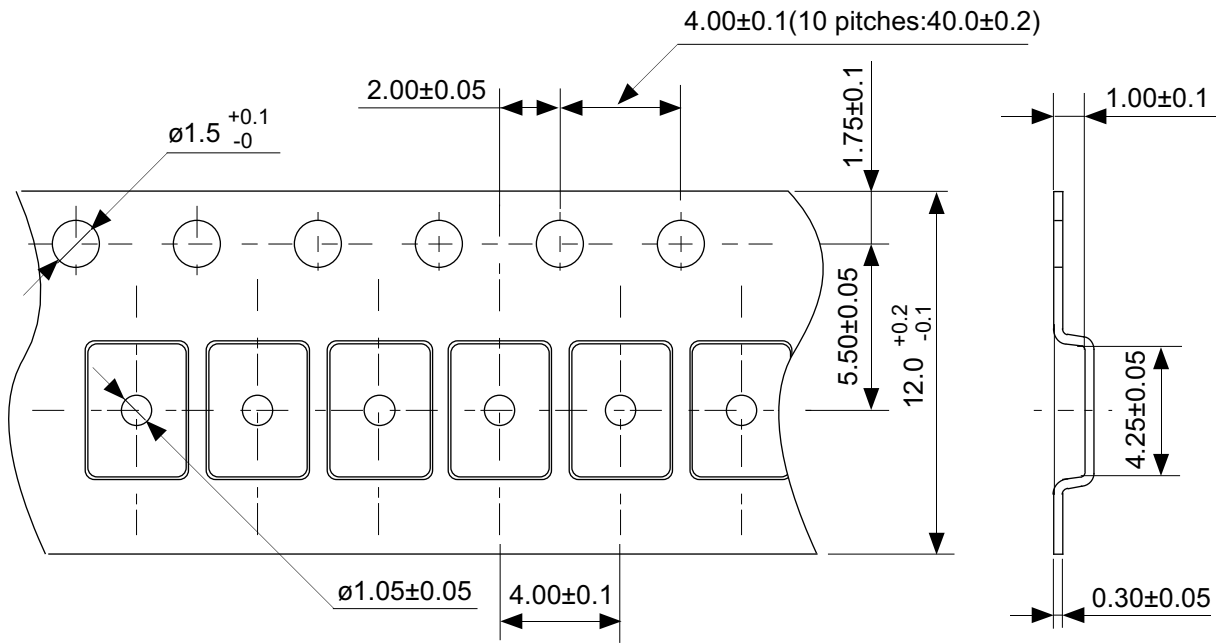
Item	Specification	
Size [mm]	114.3 x 76.2 x t1.6	
Material	FR-4	
Number of copper foil layer	4	
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070
	2	74.2 x 74.2 x t0.035
	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via	-	

No. SNT8A-A-Board-SD-1.0



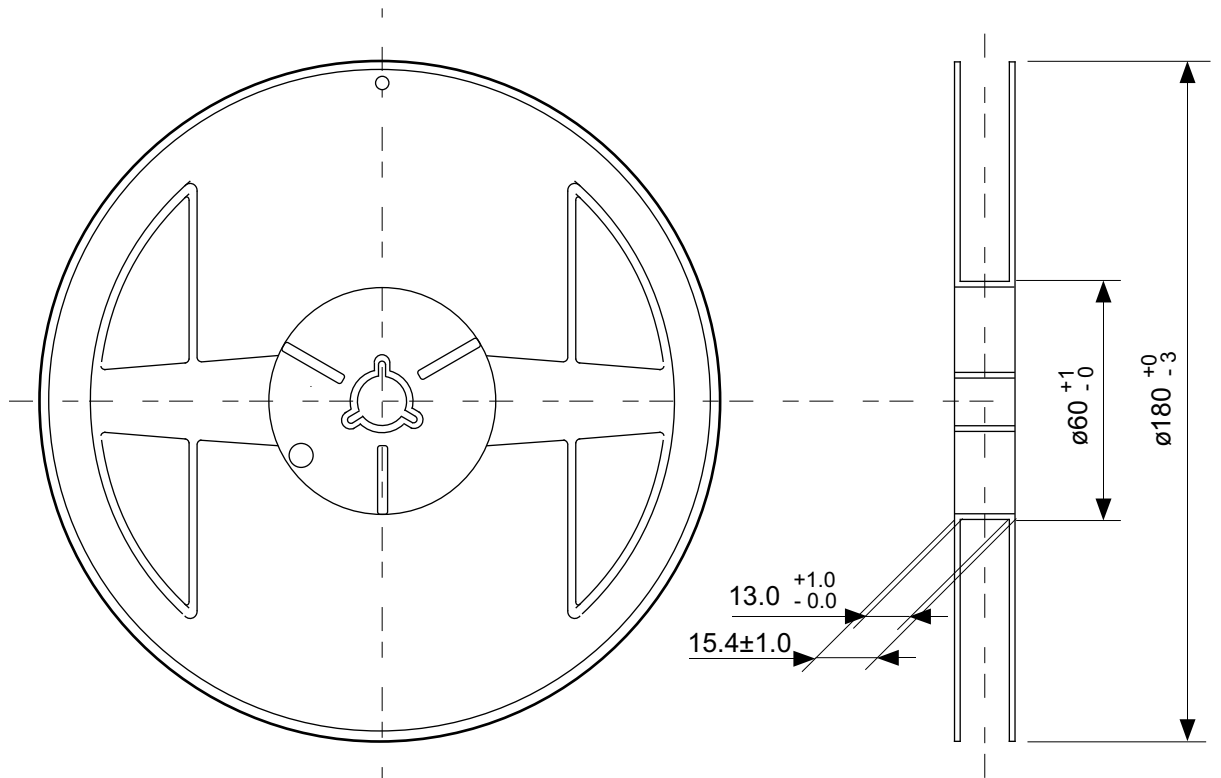
No. FM008-A-P-SD-1.2

TITLE	TMSOP8-A-PKG Dimensions
No.	FM008-A-P-SD-1.2
ANGLE	
UNIT	mm
ABLIC Inc.	

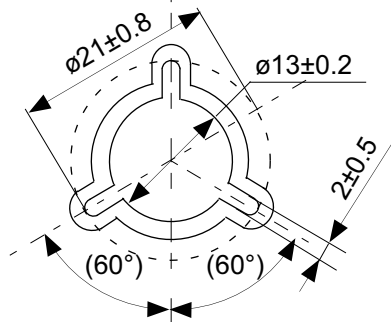


No. FM008-A-C-SD-3.0

TITLE	TMSOP8-A-Carrier Tape
No.	FM008-A-C-SD-3.0
ANGLE	
UNIT	mm
ABLIC Inc.	

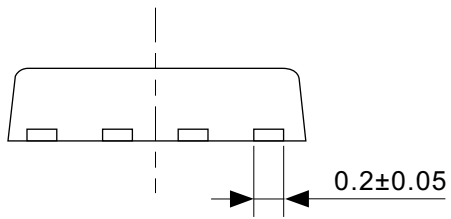
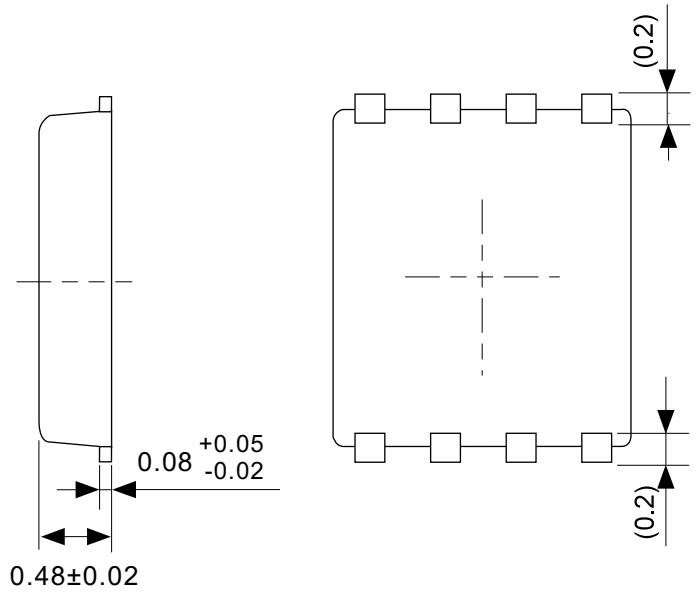
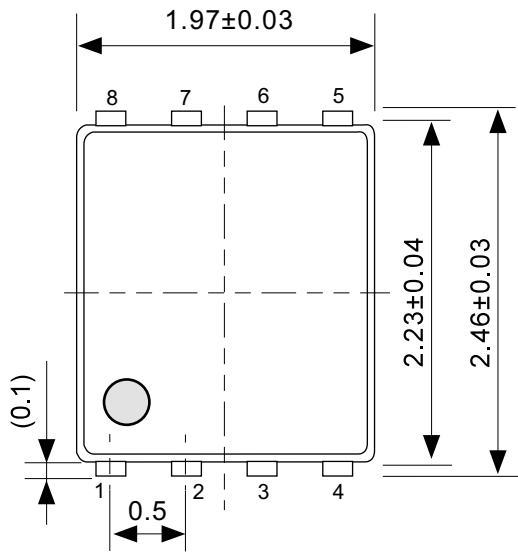


Enlarged drawing in the central part



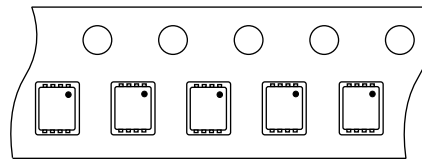
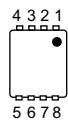
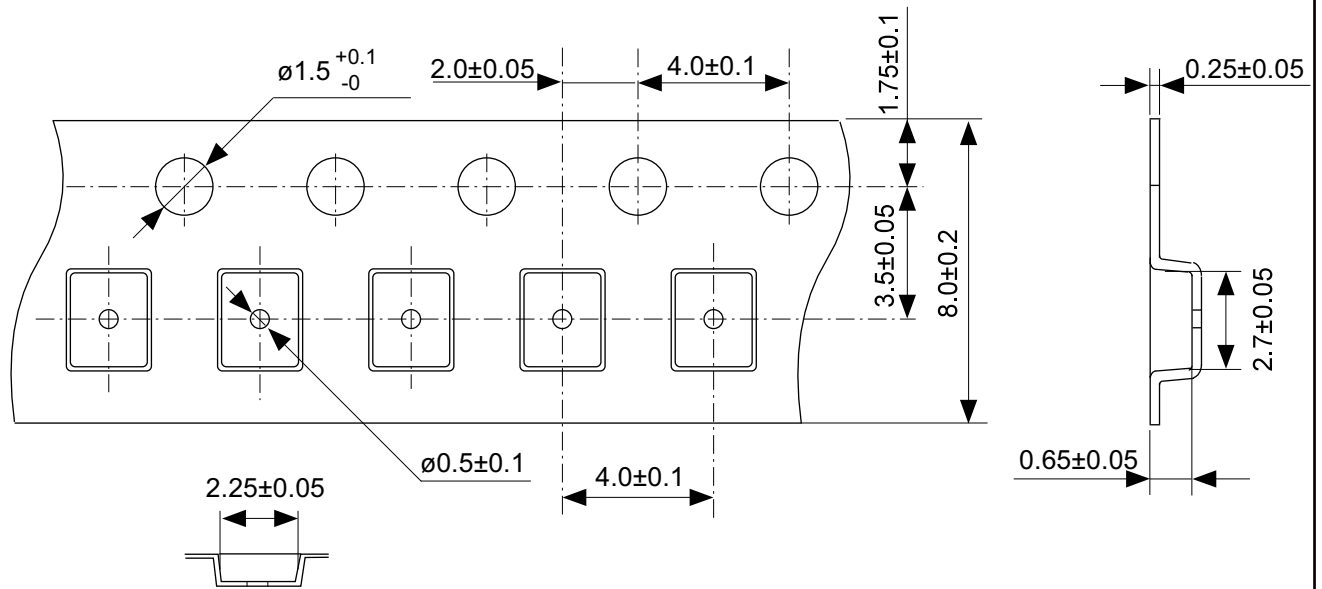
No. FM008-A-R-SD-2.0

TITLE	TMSOP8-A-Reel		
No.	FM008-A-R-SD-2.0		
ANGLE		QTY.	4,000
UNIT	mm		
ABLIC Inc.			



No. PH008-A-P-SD-2.1

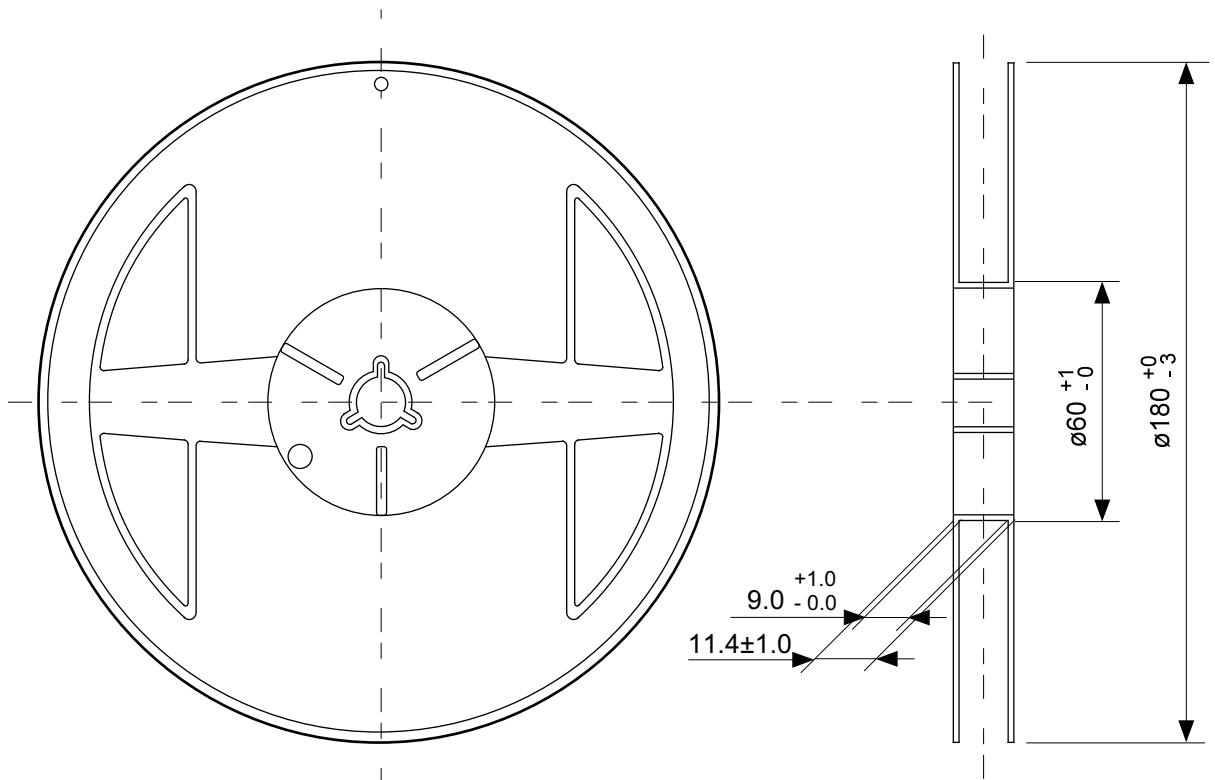
TITLE	SNT-8A-A-PKG Dimensions
No.	PH008-A-P-SD-2.1
ANGLE	
UNIT	mm
ABLIC Inc.	



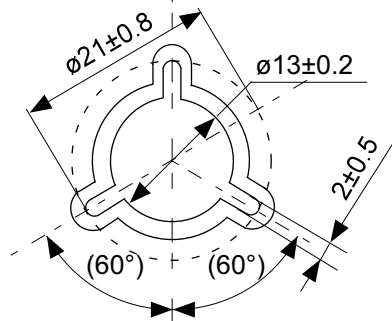
→
Feed direction

No. PH008-A-C-SD-2.0

TITLE	SNT-8A-A-Carrier Tape
No.	PH008-A-C-SD-2.0
ANGLE	
UNIT	mm
ABLIC Inc.	

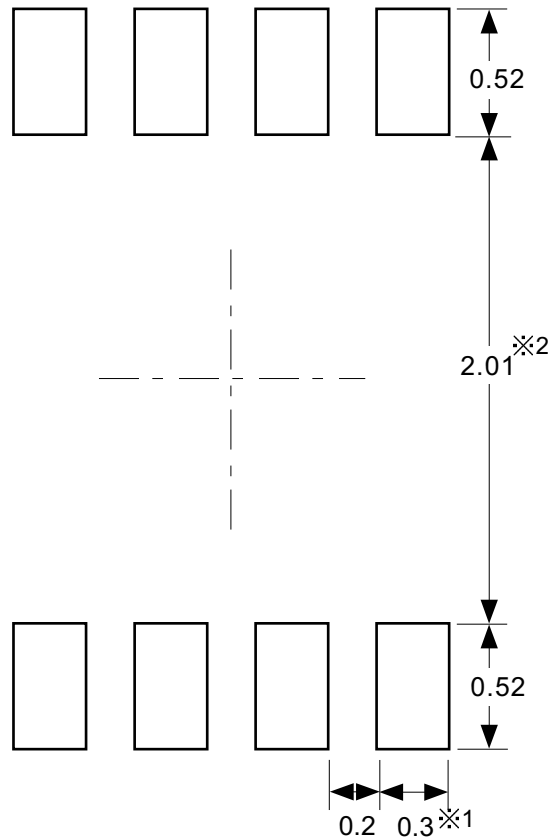


Enlarged drawing in the central part



No. PH008-A-R-SD-2.0

TITLE	SNT-8A-A-Reel		
No.	PH008-A-R-SD-2.0		
ANGLE		QTY.	5,000
UNIT	mm		
ABLIC Inc.			



※1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.).
 ※2. パッケージ中央にランドパターンを広げないでください (1.96 mm ~ 2.06 mm)。

- 注意
1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
 2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm以下にしてください。
 3. マスク開口サイズと開口位置はランドパターンと合わせてください。
 4. 詳細は“SNTパッケージ活用の手引き”を参照してください。

※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).
 ※2. Do not widen the land pattern to the center of the package (1.96 mm to 2.06mm).

- Caution**
1. Do not do silkscreen printing and solder printing under the mold resin of the package.
 2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
 3. Match the mask aperture size and aperture position with the land pattern.
 4. Refer to "SNT Package User's Guide" for details.

※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.).
 ※2. 请勿向封装中间扩展焊盘模式 (1.96 mm ~ 2.06 mm)。

- 注意
1. 请勿在树脂型封装的下面印刷丝网、焊锡。
 2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在 0.03 mm 以下。
 3. 钢网的开口尺寸和开口位置请与焊盘模式对齐。
 4. 详细内容请参阅 "SNT 封装的应用指南"。

No. PH008-A-L-SD-4.1

TITLE	SNT-8A-A -Land Recommendation
No.	PH008-A-L-SD-4.1
ANGLE	
UNIT	mm
ABLIC Inc.	

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2.4-2019.07